



Product data sheet

1. General description

Ultrafast, epitaxial rectifier diode in a TO220-2L plastic package

2. Features and benefits

- Fast switching
- Low thermal resistance
- Soft recovery characteristic
- Low forward voltage drop
- Low switching loss
- High thermal cycling performance

3. Applications

- Output rectifiers in high frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating	· · · · · · · · · · · · · · · · · · ·					
V _R	reverse voltage	Square-wave; δ = 1.0	600			V	
$I_{F(AV)}$	average forward current	δ = 0.5; T _{mb} ≤ 108 °C; Square-wave pulse; Fig. 1; Fig. 2; Fig. 3	15			A	
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 108 °C; Square-wave	30			A	
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; Sinusoidal waveform; <u>Fig. 4</u>	130			A	
		t _p = 8.3 ms; T _{j(init)} = 25 °C; Sinusoidal waveform	143			A	
Symbol	Parameter	Conditions	Min Typ Max		Unit		
Static ch	aracteristics	· · · · · · · · · · · · · · · · · · ·					
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.17	1.38	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>		-	1	1.2	V
Dynamic	characteristics						1
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s};$ $T_i = 25 \text{ °C}; Fig. 7$		-	50	60	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	A	anode	1 7 9 1	К — К — А
mb	mb	mounting base; cathode	C () (001aaa020

6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
BYT79-600	TO220-2L	BYT79-600,127	Tube	50	SOD59	27-Nov-2012		

7. Marking

Table 4. N	Table 4. Marking codes							
Type nu	mber	Marking codes						
BYT79-6	600	BYT79 600						

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V _{RWM}	crest working reverse voltage		600	V
V _R	reverse voltage	Square-wave; δ = 1.0	600	V
$I_{F(AV)}$	average forward current	δ = 0.5; T _{mb} ≤ 108 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	15	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 108 °C; Square-wave	30	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; Sinusoidal waveform; <u>Fig. 4</u>	130	A
		t _p = 8.3 ms; T _{j(init)} = 25 °C; Sinusoidal waveform	143	A
T _{stg}	storage temperature		-55 to 150	°C
T _j	junction temperature		150	°C

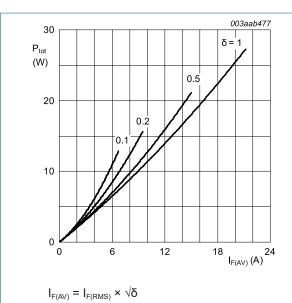
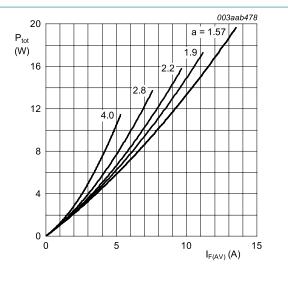


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

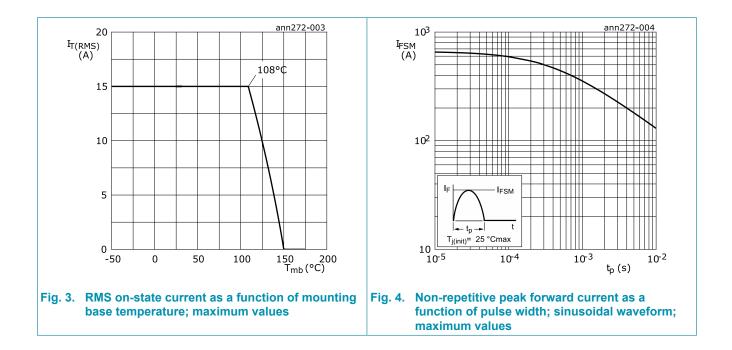


a = form factor = $I_{F(RMS)}/I_{F(AV)}$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

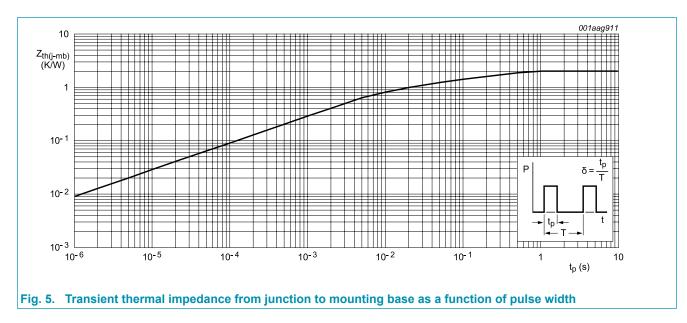
Rectifier diode ultrafast

BYT79-600



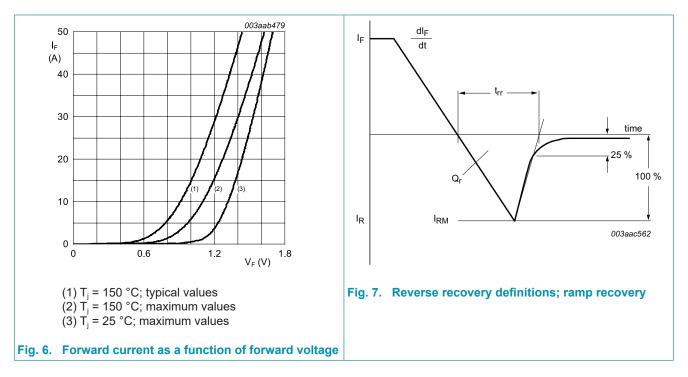
9. Thermal characteristics

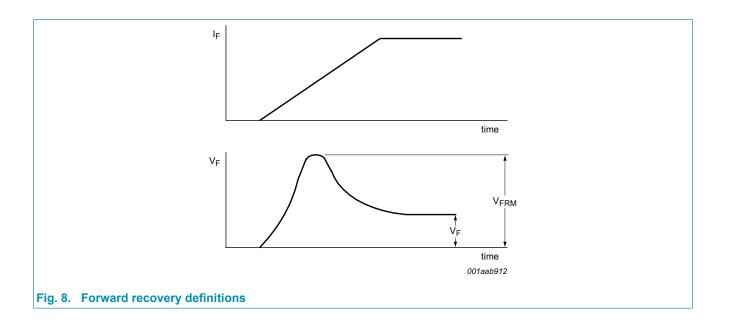
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	with heatsink compound; <u>Fig.5</u>	-	-	2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air		-	60	-	K/W



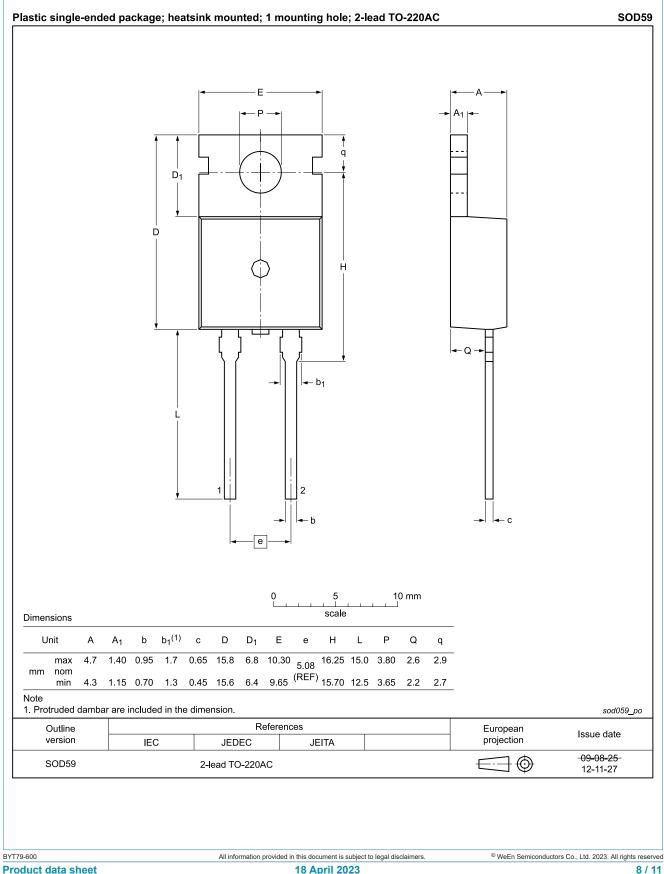
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Conditions		Тур	IVIAN	Unit
Static cha	racteristics					
V _F	forward voltage	I _F = 15 A; Τ _j = 25 °C; <u>Fig. 6</u>	-	1.17	1.38	V
		I _F = 15 A; T _j = 150 °C; <u>Fig. 6</u>	-	1	1.2	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	5	50	μA
		V _R = 600 V; T _j = 100 °C	-	0.2	0.8	mA
Dynamic	characteristics					
Q _r	recovered charge	I _F = 2 A; V _R = 30 V; dI _F /dt = 20 A/μs; <u>Fig. 7</u>	-	40	70	nC
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	50	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; \text{ d}_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 100 ^\circ\text{C}; \text{ Fig. 7}$	-	3	5.2	А
V_{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 10 A/μs; <u>Fig. 8</u>	-	3.2	-	V





11. Package outline



BYT79-600

Rectifier diode ultrafast

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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